

SB520 THRU SB5A0

Schottky Barrier Rectifiers
Reverse Voltage – 20 to 100 V
Forward Current – 5 A

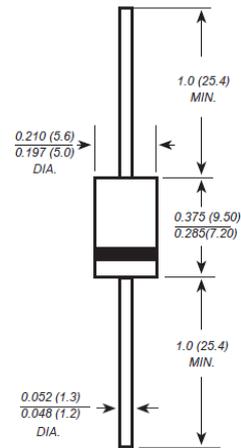
Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds at terminals, 0.375”(9.5mm) lead length, 5lb.(2.3kg) tension

Mechanical Data

- **Case:** Molded plastic body, JEDEC DO-201AD.
- **Terminals:** Axial leads, solderable per MIL-STD-750, method 2026
- **Polarity:** Color band denotes cathode end.
- **Mounting Position:** Any

DO-201AD



Dimensions in inches and (millimeters)

Absolute Maximum Ratings and Characteristics

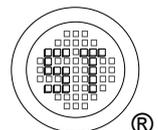
Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%

	Symbols	SB 520	SB 530	SB 540	SB 550	SB 560	SB 580	SB 5A0	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	80	100	V
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	57	71	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current 0.375” (9.5mm) lead length	$I_{(AV)}$	5							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed On Rated Load (JEDEC method)	I_{FSM}	150							A
Maximum Instantaneous Forward Voltage at 5 A ¹⁾	V_F	0.55		0.7		0.8	0.85		V
Maximum Reverse Current at Rated Reverse Voltage ¹⁾	I_R	2.5							mA
$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$		50		25					
Typical Junction Capacitance ²⁾	C_{tot}	500		400				pF	
Typical Thermal Resistance, Junction To Ambient ³⁾	$R_{\theta JA}$	25							°C/W
Typical Thermal Resistance, Junction To Lead ³⁾	$R_{\theta JL}$	8							°C/W
Operating Junction Temperature Range	T_J	-65 to +125			-65 to +150				°C
Storage Temperature Range	T_{Stg}	-65 to +150							°C

¹⁾ Pulse test: 300 μs pulse width, 1% duty cycle

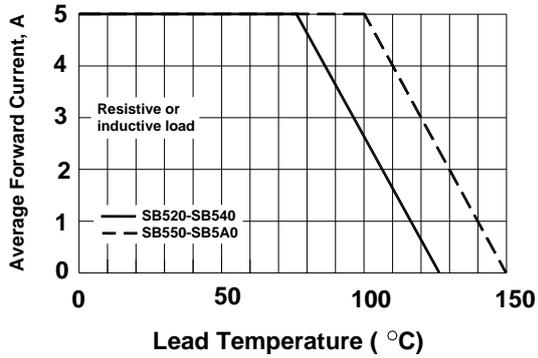
²⁾ Measured at 1MHz and applied reverse voltage of 4 V

³⁾ Thermal Resistance from Junction to lead vertical P.C.B, mounted with 0.375”(9.5mm) lead length

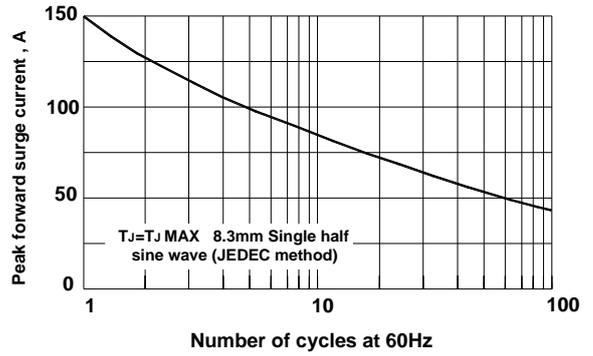


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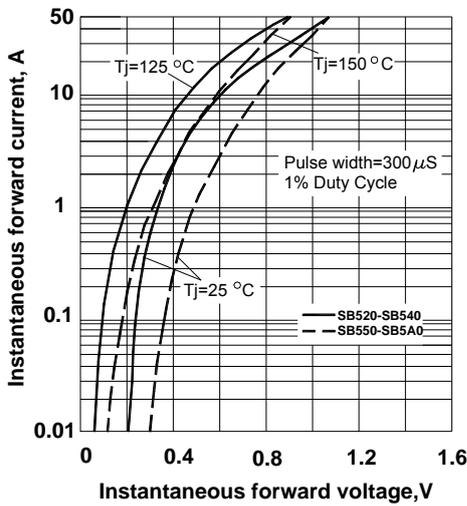
Forward Current Derating Curve



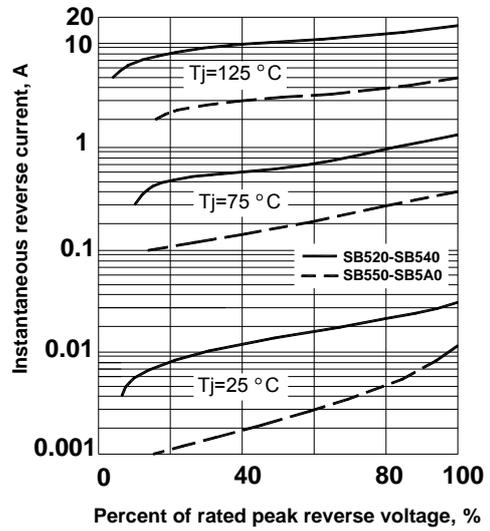
Maximum non-repetitive peak forward surge current



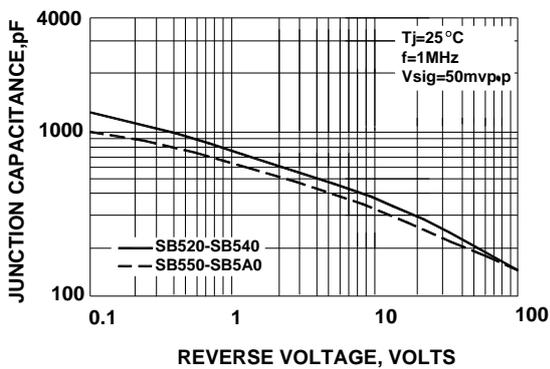
Typical instantaneous forward characteristics



Typical reverse characteristics



TYPICAL JUNCTION CAPACITANCE



TYPICAL TRANSIENT THERMAL IMPEDANCE

